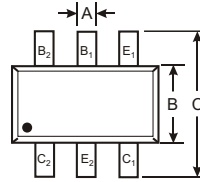


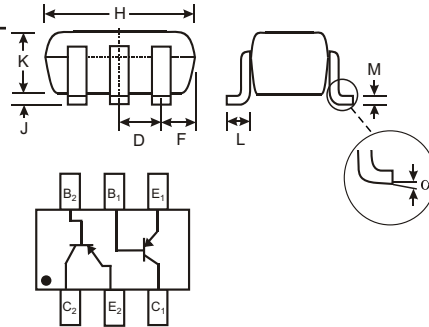
Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (IMX8)
- Small Surface Mount Package
- Also Available in Lead Free Version



Mechanical Data

- Case: SOT-26, Molded Plastic
- Case material - UL Flammability Rating Classification 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Also Available in Lead Free Plating (Matte Tin Finish). Please see Ordering Information, Note 4, on Page 2
- Terminal Connections: See Diagram
- Marking: KX7, See Page 2
- Ordering & Date Code Information: See Page 2
- Weight: 0.016 grams (approx.)



SOT-26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
F	—	—	0.55
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—
All Dimensions in mm			

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	IMT4	Unit
Collector-Base Voltage	V_{CBO}	-120	V
Collector-Emitter Voltage	V_{CEO}	-120	V
Emitter-Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-50	mA
Power Dissipation (Note 1)	P_d	225	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	555	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 2)						
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-120	—	—	V	$I_C = -50\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-120	—	—	V	$I_C = -1.0\text{mA}$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5.0	—	—	V	$I_E = -50\mu\text{A}$
Collector Cutoff Current	I_{CBO}	—	—	-0.5	μA	$V_{CB} = -100\text{V}$
Emitter Cutoff Current	I_{EBO}	—	—	-0.5	μA	$V_{EB} = -4.0\text{V}$
ON CHARACTERISTICS (Note 2)						
DC Current Gain	h_{FE}	180	—	820	—	$I_C = -2.0\text{mA}, V_{CE} = -6.0\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	—	-0.5	V	$I_C = -10\text{mA}, I_B = -1.0\text{mA}$
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f_T	—	140	—	MHz	$V_{CE} = -12\text{V}, I_E = 2.0\text{mA}, f = 100\text{MHz}$

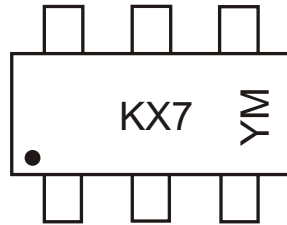
Notes: 1. Device mounted on FR-5 PCB 1.0 x 0.75 x 0.062 inch pad layout as shown on Diodes Inc. suggested pad layout AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>. 200mW per element must not be exceeded.
2. Short duration pulse test used to minimize self-heating effect.

Ordering Information (Note 3)

Device	Packaging	Shipping
IMT4-7	SOT-26	3000/Tape & Reel

Notes: 3. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.
 4. For Lead Free version (with Lead Free terminal finish) part number, please add "-F" suffix to part number above.
 Example: IMT4-7-F.

Marking Information

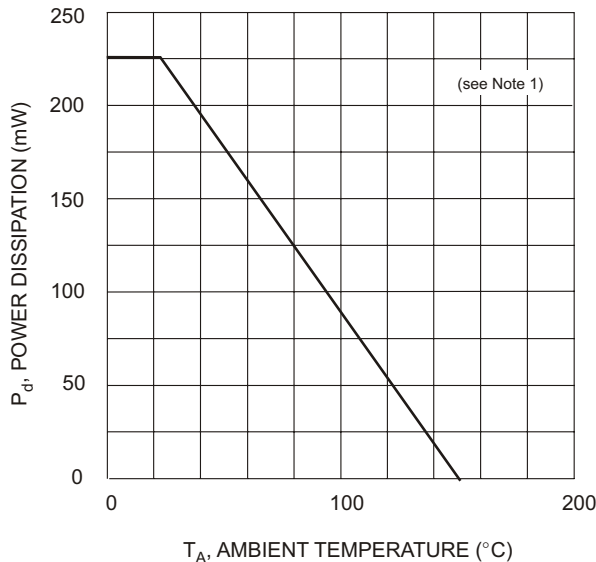


KX7 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year ex: N = 2002
 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D



T_A , AMBIENT TEMPERATURE (°C)
 Fig. 1, Power Derating Curve

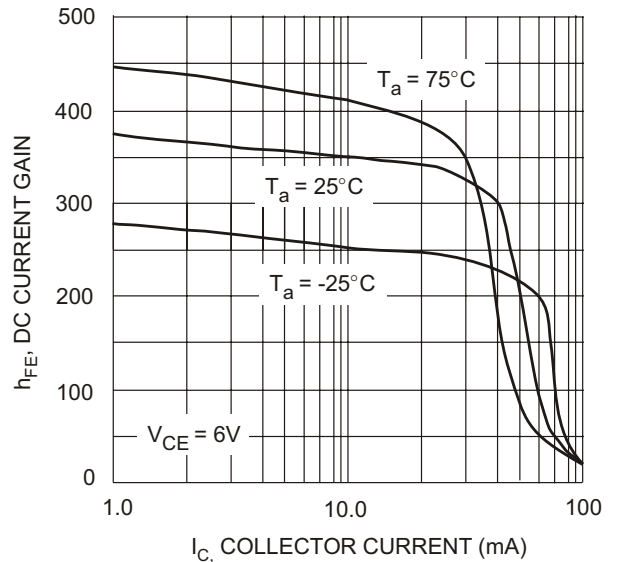
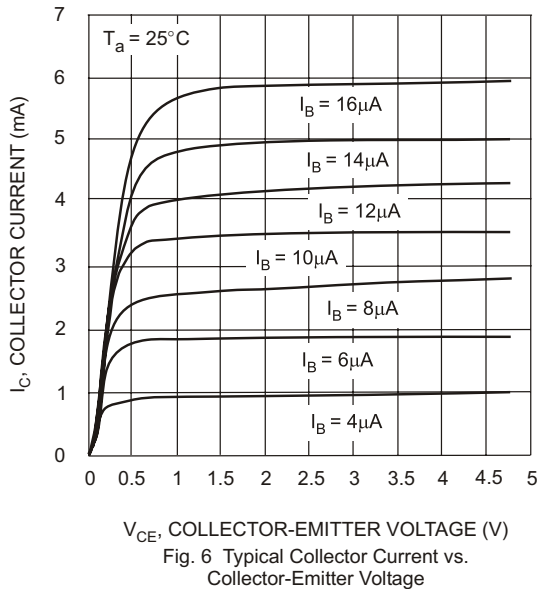
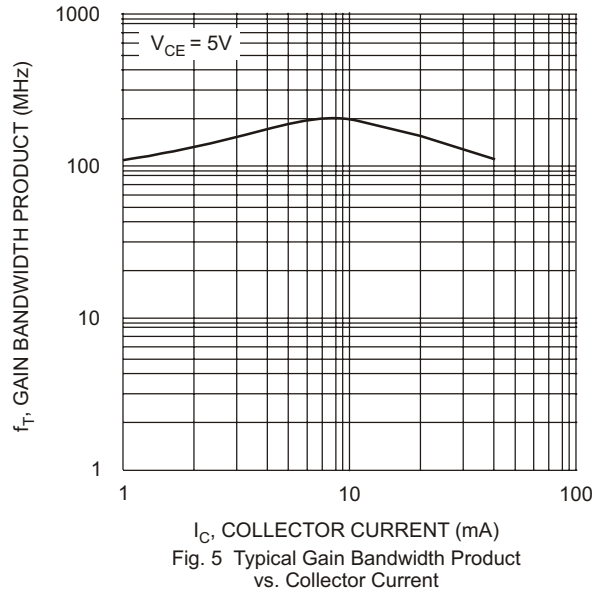
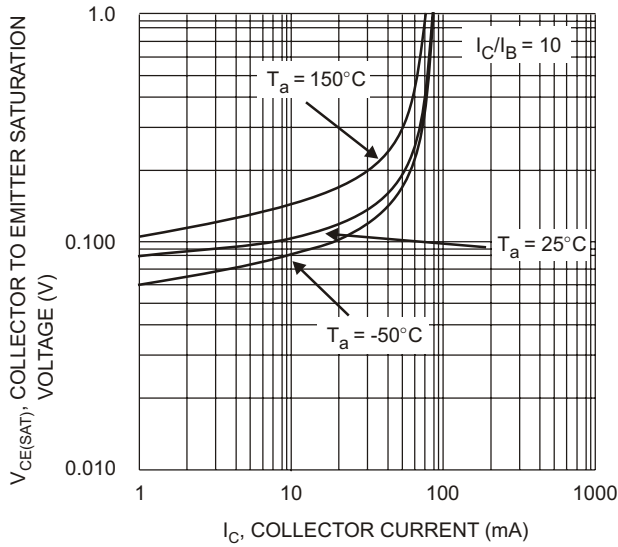
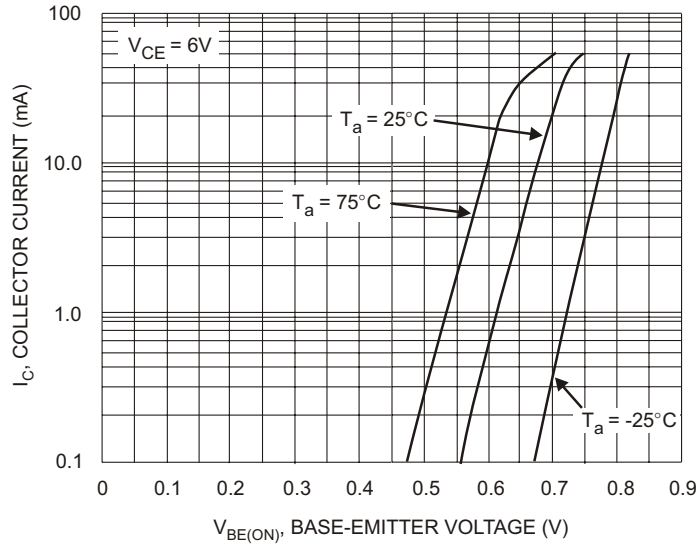


Fig. 2 Typical DC Current Gain vs. Collector Current





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